

December 1994

# 54F/74F11 Triple 3-Input AND Gate

# **General Description**

This device contains three independent gates, each of which performs the logic AND function.

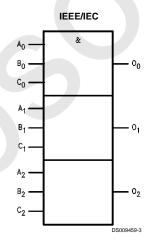
## Ordering Code: See Section 0

Commercial	Military	Package	Package Description
		Number	
74F11PC		N14A	14-Lead (0.300" Wide) Molded Dual-In-Line
	54F11DM (Note 2)	J14A	14-Lead Ceramic Dual-In-Line
74F11SC (Note 1)		M14A	14-Lead (0.150" Wide) Molded Small Outline, JEDEC
74F11SJ (Note 1)		M14D	14-Lead (0.300" Wide) Molded Small Outline, EIAJ
	54F11FM (Note 2)	W14B	14-Lead Cerpack
	54F11LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

# **Logic Symbol**



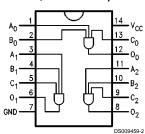
TRI-STATE® is a registered trademark of National Semiconductor Corporation.

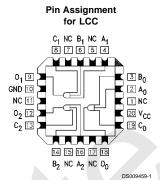
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# **Connection Diagrams**

Pin Assignment for DIP, SOIC and Flatpak





# **Unit Loading/Fan Out**

See Section 0 for U.L. definitions

		54F/74F				
Pin Names	Description	U.L.	Input I <sub>IH</sub> /I <sub>IL</sub>			
		HIGH/LOW	Output I <sub>OH</sub> /I <sub>OL</sub>			
$A_n, B_n, C_n$	Inputs	1.0/1.0	20 μA/-0.6 mA			
$O_n$	Outputs	50/33.3	–1 mA/20 mA			
		-				

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DOVE

## **Absolute Maximum Ratings** (Note 3)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

 Storage Temperature
 -65°C to +150°C

 Ambient Temperature under Bias
 -55°C to +125°C

 Junction Temperature under Bias
 -55°C to +175°C

 Plastic
 -55°C to +150°C

V<sub>CC</sub> Pin Potential to

Ground Pin -0.5V to +7.0V Input Voltage (Note 4) -0.5V to +7.0V Input Current (Note 4) -30 mA to +5.0 mA

Voltage Applied to Output

in HIGH State (with  $V_{CC} = 0V$ )

 $\begin{array}{lll} \mbox{Standard Output} & -0.5 \mbox{V to V}_{\rm CC} \\ \mbox{TRI-STATE} \mbox{Output} & -0.5 \mbox{V to } +5.5 \mbox{V} \end{array}$ 

Current Applied to Output

in LOW State (Max)  $\qquad \qquad \text{twice the rated I}_{\text{OL}} \ (\text{mA})$ 

# Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

**Note 3:** Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

#### **DC Electrical Characteristics**

Symbol	Parameter		54F/74F			Units	V <sub>cc</sub>	Conditions	
			Min	Тур	Max				
V <sub>IH</sub>	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal		
V <sub>IL</sub>	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V <sub>CD</sub>	Input Clamp Diode Voltage				-1.2	V	Min	I <sub>IN</sub> = -18 mA	
V <sub>OH</sub>	Output HIGH	54F 10% V <sub>CC</sub>	2.5					I <sub>OH</sub> = -1 mA	
	Voltage	74F 10% V <sub>CC</sub>	2.5			V	Min	I <sub>OH</sub> = -1 mA	
		74F 5% V <sub>CC</sub>	2.7					I <sub>OH</sub> = -1 mA	
V <sub>OL</sub>	Output LOW	54F 10% V <sub>CC</sub>			0.5	V	Min	I <sub>OL</sub> = 20 mA	
	Voltage	74F 10% V <sub>CC</sub>			0.5			I <sub>OL</sub> = 20 mA	
I <sub>IH</sub>	Input HIGH	54F			20.0	μA	Max	V <sub>IN</sub> = 2.7V	
	Current	74F			5.0				
I <sub>BVI</sub>	Input HIGH Current	54F			100	μA	Max	V <sub>IN</sub> = 7.0V	
	Breakdown Test	74F			7.0				
I <sub>CEX</sub>	Output HIGH	54F			250	μΑ	Max	V <sub>OUT</sub> = V <sub>CC</sub>	
	Leakage Current	74F			50				
V <sub>ID</sub>	Input Leakage	74F	4.75			V	0.0	I <sub>ID</sub> = 1.9 μA	
	Test							All other pins grounded	
I <sub>OD</sub>	Output Leakage	74F			3.75	μA	0.0	V <sub>IOD</sub> = 150 mV	
	Circuit Current							All other pins grounded	
I <sub>IL</sub>	Input LOW Current				-0.6	mA	Max	V <sub>IN</sub> = 0.5V	
Ios	Output Short-Circuit C	urrent	-60		-150	mA	Max	V <sub>OUT</sub> = 0V	
Іссн	Power Supply Current			4.1	6.2	mA	Max	V <sub>O</sub> = HIGH	
I <sub>CCL</sub>	Power Supply Current			6.5	9.7	mA	Max	V <sub>O</sub> = LOW	

#### **AC Electrical Characteristics**

See Section 0 for Waveforms and Load Configurations

	Daniel de la constant	$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_1 = 50 \text{ pF}$		54F T <sub>A</sub> , V <sub>CC</sub> = Mil C <sub>L</sub> = 50 pF		74F T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF		Units	Fig. No.	
Oh. ad										
Symbol	Parameter									
		Min	Тур	Max	Min	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	3.0	4.2	5.6	2.5	7.5	3.0	6.6	ns	<b>**-**</b>
t <sub>PHL</sub>	$A_n$ , $B_n$ , $C_n$ to $O_n$	2.5	4.1	5.5	2.0	7.5	2.5	6.5		

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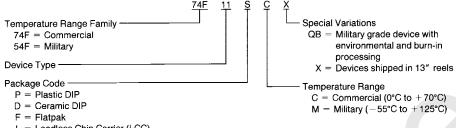
Extrac End

**Proof** 



# Ordering Information The device number is used to form

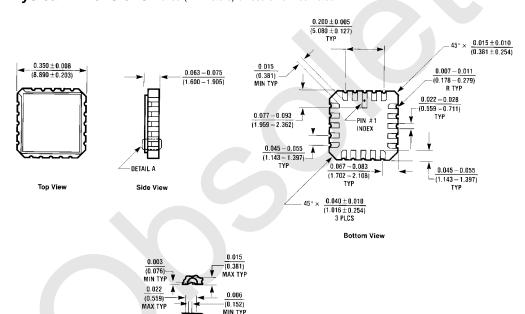
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



L = Leadless Chip Carrier (LCC)
S = Small Outline SOIC JEDEC

### Physical Dimensions inches (millimeters) unless otherwise noted

SJ = Small Outline SOIC EIAJ



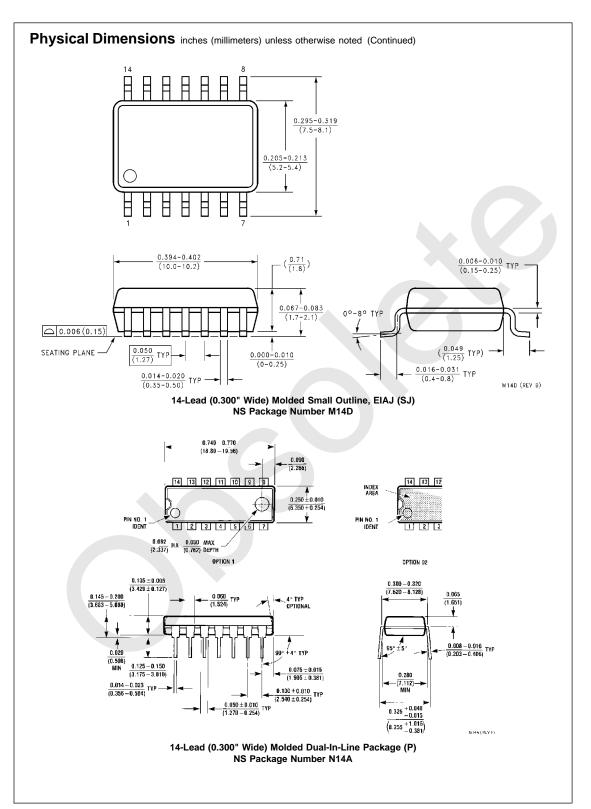
20-Lead Ceramic Leadless Chip Carrier (L) NS Package Number E20A

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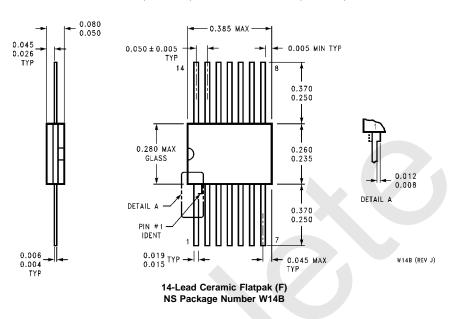
DS009459.

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### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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